UMW 2N65

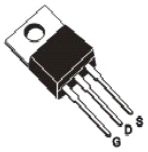
650V N-Channel MOSFET

1.Features

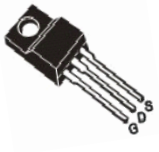
- $V_{DS\ (V)}$=650V
- I_D=2A
- $R_{DS(ON)}$=4.5Ω

2.Pinning information

Pin	Symbol	Description
1	G	GATE
2	D	DRAIN
3	S	SOURCE



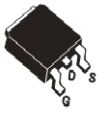
TO-220



TO-220F



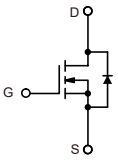
TO-251



TO-252



TO-223



N-Channel

3.Absolute Maximum Ratings T_C= 25°C

Parameter		Symbol	Rating	Units
Drain-source Voltage		V_{DS}	650	V
gate-source Voltage		V_{GS}	±30	V
Continuous Drain Current	T_C=25°C	I_D	2*	A
Continuous Drain Current	T_C=100°C	I_D	1.25*	A
Drain Current －Pulsed ①		I_{DM}	8*	A
Power Dissipation	TO-220	P_{tot}	40	W
	TO-220F		21	W
	TO-251/TO-252		28	W
Junction Temperature		T_J	150	°C
Storage Temperature		T_{STG}	-55 to 150	°C
Single Pulse Avalanche Energy ②		E_{AS}	120	mJ

*Drain current limited by maximum junction temperature

4.Thermal Resistance Rating

Parameter	Symbol	MAX		Units
		TO-220	TO-220F	
Thermal Resistance Junction-lead	R_{thJL}	2.31	5.43	°C/W
Thermal Resistance Junction-ambient	R_{thJA}	62.5	62.5	°C/W

5.Electrical Characteristic (T_C=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Drain-source Breakdown Voltage	BV_{DSS}	V_{GS}=0V, I_D=250μA	650			V
Breakdown Voltage Temperature Coefficient	$\frac{\Delta BV_{DSS}}{\Delta T_J}$	I_D=250μA Referenced to 25°C		0.6		V/°C
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=250μA	2		4	V
Drain-source Leakage Current	I_{DSS}	V_{DS}=650V, V_{GS}=0V, T_J=25°C			25	μA
		V_{DS}=520V, V_{GS}=0V, T_J=125°C			250	μA
Gate-body Leakage Current (V_{DS}=0)	I_{GSS}	V_{GS}=±30V			±100	nA
Static Drain-source On Resistance	$R_{DS(ON)}$	V_{GS}=10V, I_D=1A ③		4.5	5.5	Ω
Input capacitance	C_{iss}	V_{GS}=0V, V_{DS}=25V, f=1MHz		311		pF
Turn -Off Delay Time	$t_{D(off)}$	V_{DD}=300V, I_D=2A, R_G=25Ω ③		24		ns
Total Gate Charge	Q_g	I_D=2A, V_{DS}=520V, V_{GS}=10V ③		14.5		nC
Gate-to-Source Charge	Q_{gs}			1.8		nC
Gate-to-Drain Charge	Q_{gd}			8.3		nC
Continuous Diode Forward Current	I_S				2	A
Diode Forward Voltage	V_{SD}	T_J=25°C, I_S=2A, V_{GS}=0V ③			1.4	V
Reverse Recovery Time	t_{rr}	T_J=25°C, I_F=2A di/dt=100A/μs ③		368		ns
Reverse Recovery Charge	Q_{rr}			1		nC

Notes:

① Repetitive rating: Pulse width limited by maximum junction temperature.

② Starting T_J=25°C, V_{DD} =50V, L=56mH, R_G =25Ω, I_{AS}=2A.

③ Pulse Test : Pulse width ≤ 300μs, Duty cycle ≤ 2%.

6.1Typical Characteristic

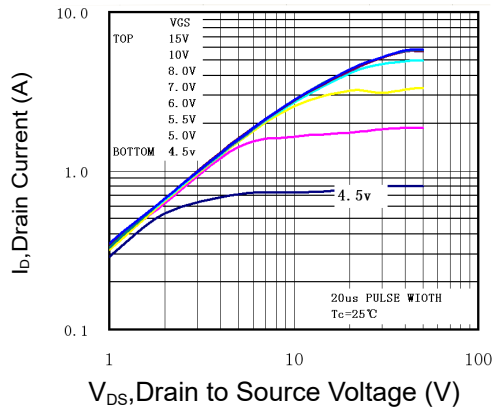


Figure 1: Typical Output Characteristics, Tc=25°C

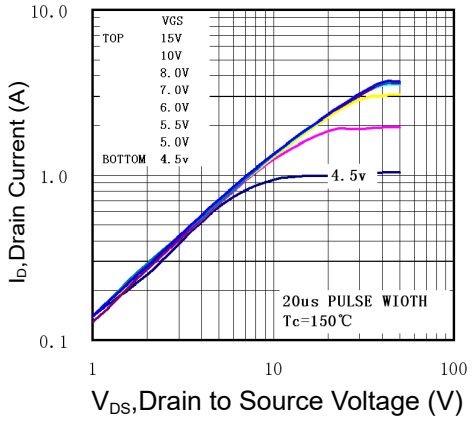


Figure 2: Typical Output Characteristics, Tc=150°C

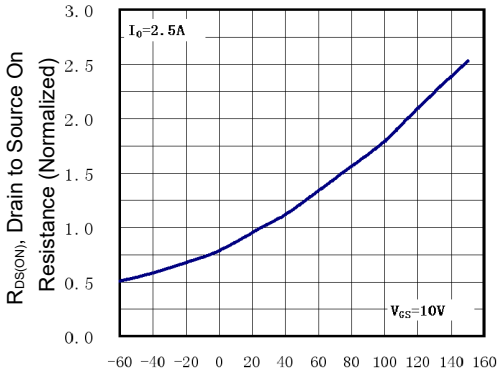


Figure 3: Normalized On-Resistance Vs.Temperature

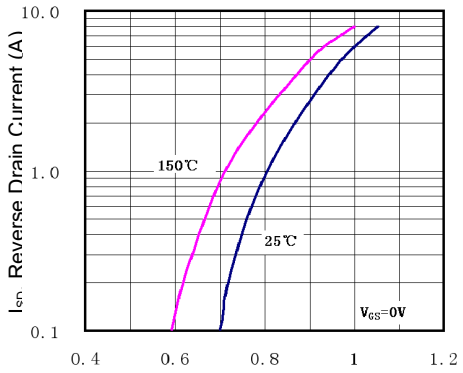


Figure 4: Typical Source-Drain Diode Forward Voltage

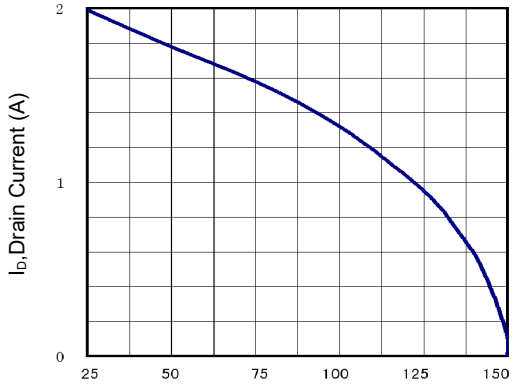


Figure 5: Maximum Drain Current Vs.Case Temperature

6.2Typical Characteristic

2N65 (TO-126&126S)

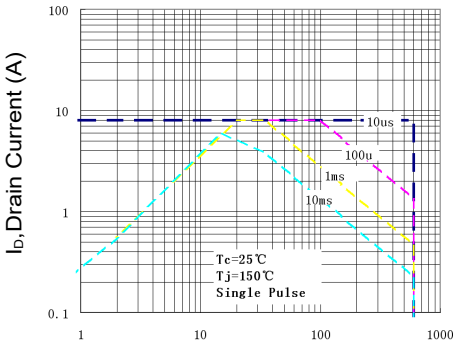


Figure 6: Maximum Safe Operating Area

2N65 (TO-220)

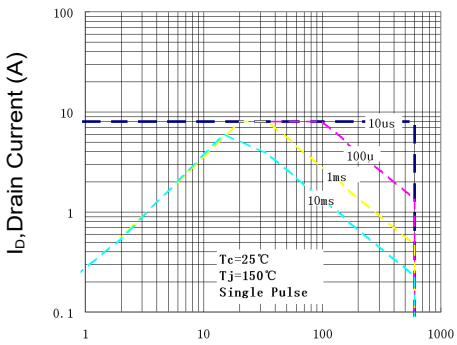


Figure 7: Maximum Safe Operating Area

2N65 (TO-220F)

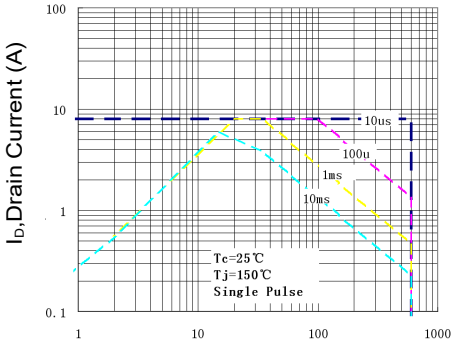
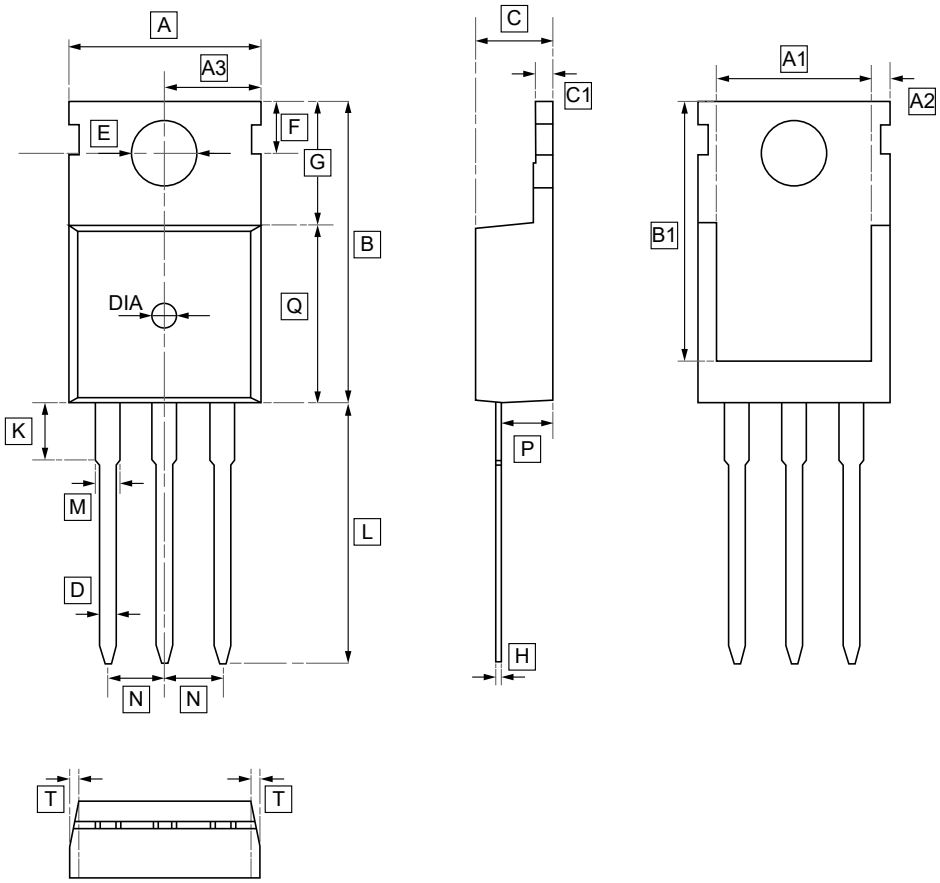


Figure 8: Maximum Safe Operating Area

7.1 TO-220 Package Outline Dimensions

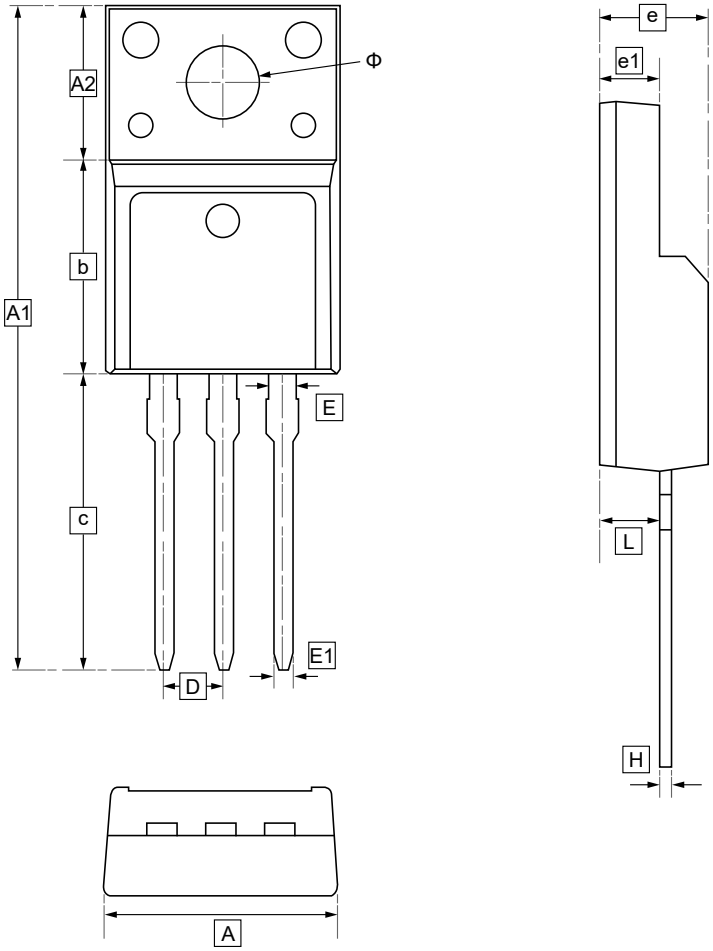


DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	A3	B	B1	C	C1	D	E	F	G
Min	9.7	8.44	1.05	4.8	15.4	12.9	4.28	1.1	0.6	3.4	2.65	5.2
Max	10.3	8.84	1.25	5.2	16.2	13.5	4.68	1.5	1.0	3.8	3.25	5.8

Symbol	H	K	L	L1	M	N	P	Q	T	DIA
Min	0.4	2.9	12.8	2.7	1.15	2.49	2.1	8.7	W:0.35	⊙1.5
Max	0.6	3.3	13.6	3.3	1.35	2.59	2.7	9.3		(deep 0.2)

7.2 TO-220F Package Outline Dimensions

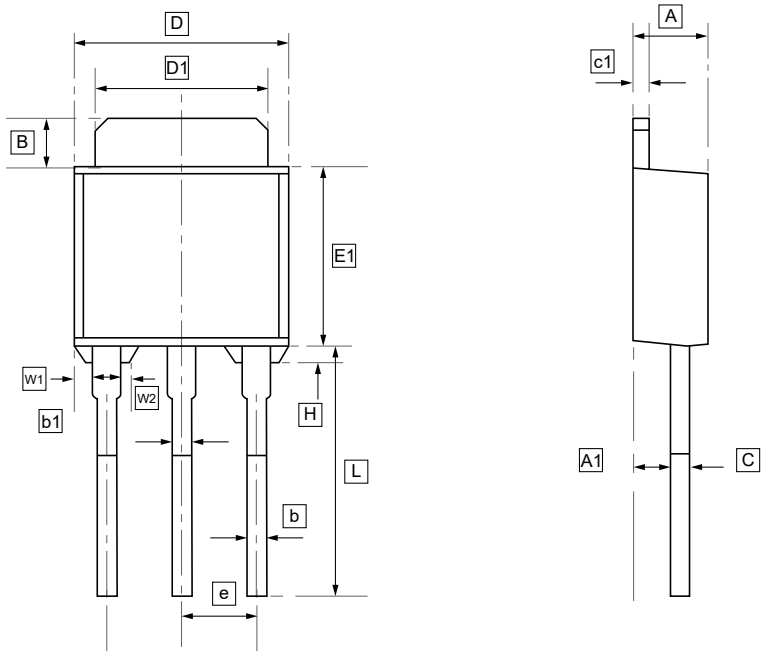


DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	b	c	D	E	E1	Φ	e	e1	L
Min	10.00	28.80	6.58	9.12	12.95	2.54	1.15	0.75	3.13	4.50	2.40	2.50
Max	10.20	29.20	6.78	9.32	13.25		1.25	0.85	3.23	4.70	2.60	2.70

Symbol	H
Min	0.45
Max	0.55

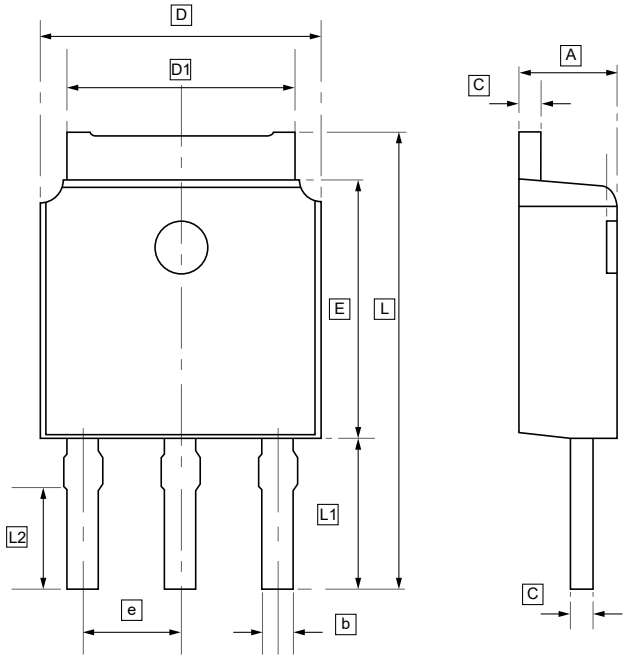
7.3 TO-251T (IPAK) Package Outline Dimensions



DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	B	b	b1	c	c1	D	D1	E	e	L	H	W1	W2
Min	2.10	0.95	0.80	0.50	0.70	0.45	0.45	6.35	5.10	5.30	2.25	7.00	0.35	0.30	0.20
Max	2.50	1.30	1.25	0.80	0.80	0.70	0.70	6.80	5.50	6.30	2.35	9.20	0.45	0.50	0.40

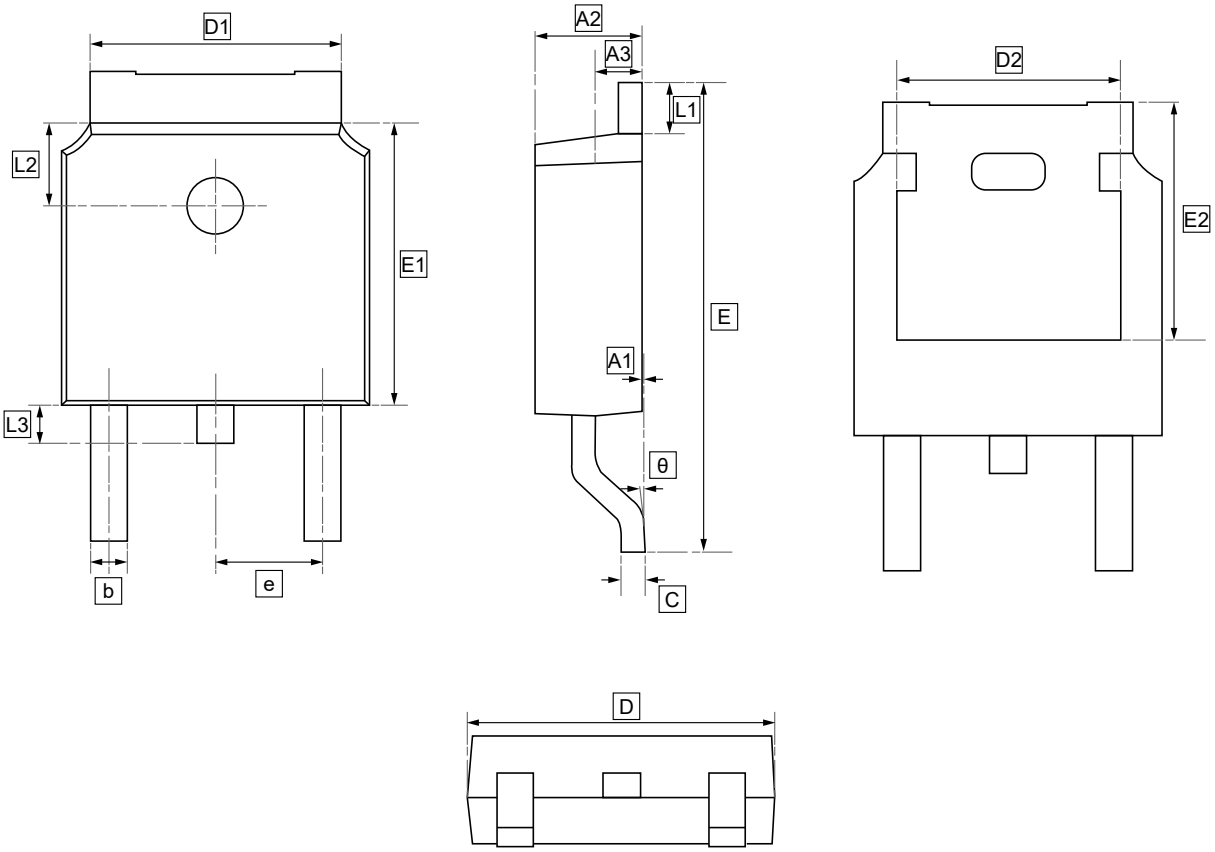
7.4 TO-251S Package Outline Dimensions



DIMENSIONS (mm are the original dimensions)

Symbol	A	b	C	D	D1	E	e	L	L1	L2
Min	2.20	0.60	0.45	6.50	5.10	5.9	2.18	11.00	4.8	3.5
Max	2.40	0.85	0.60	6.70	5.50	6.20	2.38	12.40	5.3	4.2

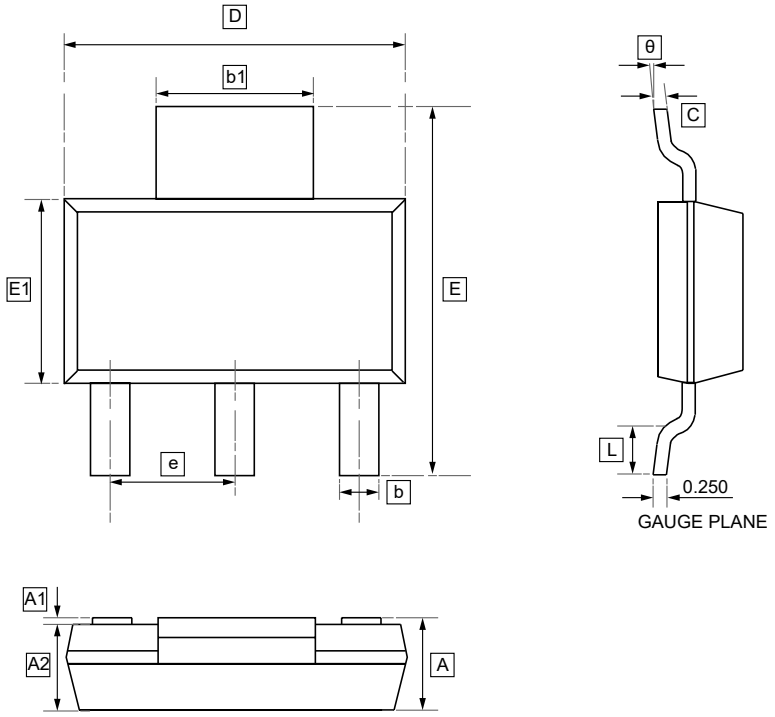
7.5 TO-252 Package Outline Dimensions



DIMENSIONS (mm are the original dimensions)

Symbol	A1	A2	A3	b	c	D	D1	D2	E	E1	E2	e	L1	L2	L3	θ
Min	0.00	2.18	0.90	0.65	0.46	6.35	4.95	4.32	9.40	5.97	5.21	2.286	0.89	1.70	0.60	0.00
Max	0.13	2.39	1.10	0.85	0.61	6.73	5.46	4.90	10.41	6.22	5.38	BSC	1.27	1.90	1.00	8.00

7.6 SOT-223 Package Outline Dimensions

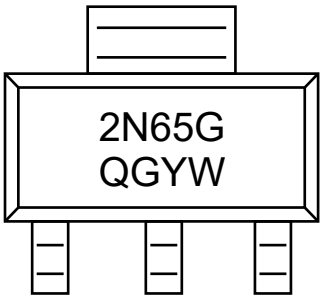


DIMENSIONS (mm are the original dimensions)

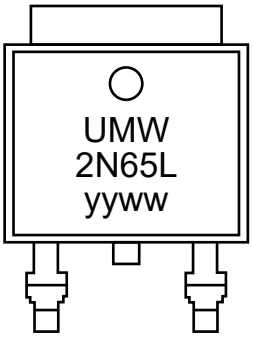
Symbol	A	A1	A2	b	b1	c	D	E	E1	e	L	θ
Min	-	0.020	1.500	0.660	2.900	0.230	6.300	6.700	3.300	2.300	0.750	0°
Max	1.800	0.100	1.700	0.840	3.100	0.350	6.700	7.300	3.700	BSC	-	10°

8.Ordering Information

SOT-223



TO-252



yy: Year Code
ww: Week Code

Order Code	Marking	Package	Base QTY	Delivery Mode
UMW 2N65G	2N65G	SOT-223	2500	Tape and reel
UMW 2N65L	2N65L	TO-252	2500	Tape and reel

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